

L Number	Hits	Search Text	DB	Time stamp
3	395	moisture and alcohol and gate and source and drain	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/06/24 19:05
4	129	moisture and alcohol and gate and source and drain and metal adj oxide and heat\$4	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/06/24 19:07
5	0	moisture adj sensor and alcohol adj sensor and gate and source and drain and metal adj oxide and heat\$4	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/06/24 19:07
6	0	moisture adj sensor and alcohol adj sensor and gate and source and drain	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/06/24 19:07
7	23	moisture same alcohol and gate and source and drain	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/06/24 19:08
8	6	moisture same alcohol same (detect\$4 or sens\$4 or determin\$4 or assay or test\$4 or measur\$4 or monitor\$4) and gate and source and drain	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/06/24 19:09
-	3	"10110471"	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/06/17 15:45
-	1	fleisher and meixner	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/06/17 16:09
-	12	gas adj sensitive adj field adj effect adj transistor	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/06/17 16:28
-	102542	field adj effect adj transistor	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/06/17 16:28
-	1704	gas same field adj effect adj transistor	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/06/17 16:28
-	969	gas same field adj effect adj transistor and drain and source and gate	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/06/17 16:29
-	1	gas same field adj effect adj transistor and drain and source and gate and polycyclopentylsilsesquioxane	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/06/17 16:29
-	5	gas same field adj effect adj transistor and drain and source and gate and silsesquioxane	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/06/17 16:31
-	1	gas same field adj effect adj transistor and drain and source and gate and polysilsesquioxane	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/06/17 16:35
-	16	drain and source and gate and polysilsesquioxane	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/06/17 16:35
-	4	gas same field adj effect adj transistor and drain and source and gate and scandium adj oxide	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/06/17 16:36

-	189	drain and source and gate and scandium adj oxide	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/06/17 16:36
-	16	drain and source and gate and scandium adj oxide and alcohol	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/06/17 16:37
-	37	drain and source and gate and scandium adj oxide and gas	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/06/17 16:53
-	195997	drain and source and gate	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/06/17 16:39
-	86	drain and source and gate and gas and substrate and polysiloxane	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/06/17 16:54
-	48	drain and source and gate and gas and substrate and polysiloxane and alcohol	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/06/17 17:20
-	2093	drain and source and gate and gas and substrate and moisture	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/06/17 17:21
-	17	drain and source and gate and gas and substrate and moisture adj sensitive	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/06/17 17:21